

Technical Data Data Sheet N1031, Rev. A

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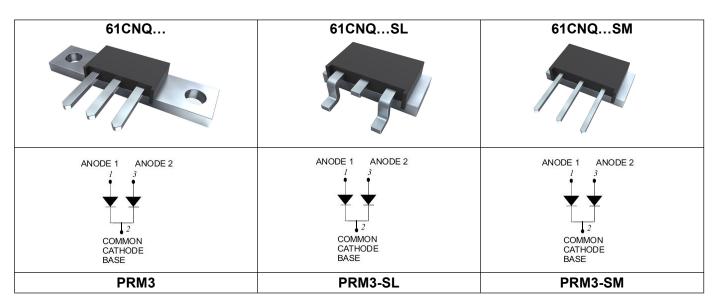
61CNQ SERIES SCHOTTKY RECTIFIER

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features

- 175℃ T_J operation
- Center tap module
- Very Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Low profile, high current package
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request



Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	35(61CNQ035) 40(61CNQ040) 45(61CNQ045)	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _c =149°C, rectangular wave form	30(Per Leg) 60(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per leg)	I _{FSM}	8.3 ms, half Sine pulse	990	А
Non-Repetitive Avalanche Energy (Peg leg)	Eas	TJ=25℃,I _{AS} =6A,L=2.2mH	40	mJ
Repetitive Avalanche Current(Peg leg)	I _{AR}	Current decaying linearly to zero in 1 µsec Frequency limited by T_J max. V_A =1.5× V_R typical	6	А

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Electrical Characteristics:

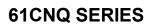
Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (Per leg) *	V _{F1}	@ 30A, Pulse, T _J = 25 °C @ 60A, Pulse, T _J = 25 °C	0.55 0.65	0.61 0.68	V
	V _{F2}	@ 30A, Pulse, T _J = 125 °C @ 60A, Pulse, T _J = 125 °C	0.49 0.60	0.55 0.66	V
Reverse Current (Per leg) *	I _{R1}	$@V_R = rated V_{R, T_J} = 25 \circ C$	0.02	5	mA
	I _{R2}	$@V_R = rated V_{R,} T_J = 125 \degree C$	5	45	mA
Junction Capacitance (Per leg)	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	2156	2600	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/µs

* Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units	
Junction Temperature	TJ	-	-55 to +175	0°	
Storage Temperature	T _{stg}	-	-55 to +175	°C	
Typical Thermal Resistance Junction to Case (per leg)	R _{θJC}	DC operation	0.5	°C/W	
Typical Thermal Resistance Junction to Case (per package)	R _{θJC}	DC operation	0.25	°C/W	
Typical Thermal Resistance, case to Heat Sink	$R_{ hetacs}$	Mounting surface, smooth and greased	0.21	°C/W	
Mounting Torque	ТМ		40(min)	Kg-cm	
Mounting Torque	1 171	-	58(max)	Ng-Cill	

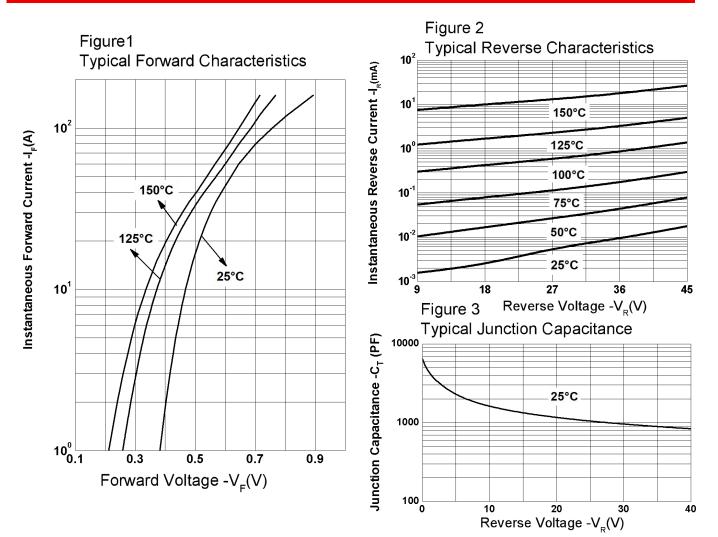
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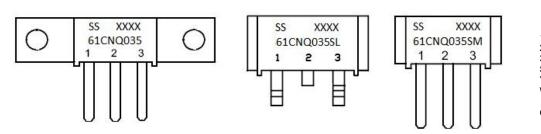
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Ratings and Characteristics Curves



Marking Diagram



Where XXXX is YYWW

1st row SS YYWWL 2nd row 61CNQ035/SL/SM 3rd row 1 2 3 (pin) SS = SS YY = Year WW = Week

Cautions: Molding resin Epoxy resin UL:94V-0

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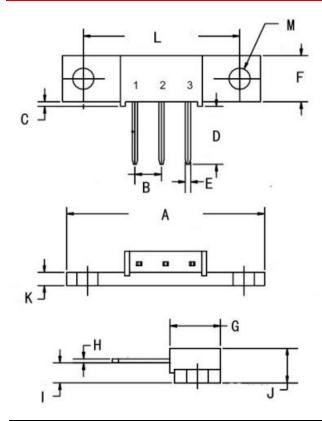
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Ordering Information



Device	Package	Approximate Weight(g)	Terminals finish	Baseplate finish	Shipping
61CNQ035	PRM3	8.6	Nickel plated	Nickel plated	48pcs / box
61CNQ035S2	PRM3	8.6	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box
61CNQ040	PRM3	8.6	Nickel plated	Nickel plated	48pcs / box
61CNQ040S2	PRM3	8.6	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box
61CNQ045	PRM3	8.6	Nickel plated	Nickel plated	48pcs / box
61CNQ045S2	PRM3	8.6	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box
61CNQ035SL	PRM3-SL	5.3	Pure Sn plated	Pure Sn plated	100pcs / box
61CNQ040SL	PRM3-SL	5.3	Pure Sn plated	Pure Sn plated	100pcs / box
61CNQ045SL	PRM3-SL	5.3	Pure Sn plated	Pure Sn plated	100pcs / box
61CNQ035SM	PRM3-SM	5.6	Nickel plated	Nickel plated	48pcs / box
61CNQ035SMS2	PRM3-SM	5.6	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box
61CNQ040SM	PRM3-SM	5.6	Nickel plated	Nickel plated	48pcs / box
61CNQ040SMS2	PRM3-SM	5.6	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box
61CNQ045SM	PRM3-SM	5.6	Nickel plated	Nickel plated	48pcs / box
61CNQ045SMS2	PRM3-SM	5.6	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box

Mechanical Dimensions PRM3 (Inches/Millimeters)



SYMBOL	MillImeters		Inches	
	Min.	Max.	Min.	Max.
A	37.72	38.23	1.485	1.506
В	5.08		0.200	
С	0.62	1.02	0.024	0.040
D	10.38	12.98	0.408	0.511
E	0.88	1.22	0.034	0.048
F	8.46	9.06	0.333	0.357
G	9.24	9.85	0.363	0.388
Н	0.61	0.92	0.024	0.037
I	3.19	4.19	0.125	0.165
J	6.95	7.55	0.273	0.298
К	2.40	2.60	0.094	0.103
L	29.51	30.40	1.161	1.197
М	3.75	4.33	0.147	0.171

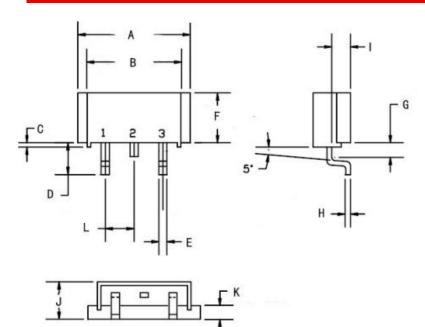
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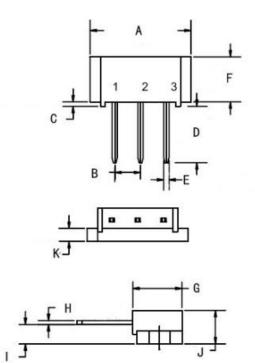
Mechanical Dimensions PRM3-SL (Inches/Millimeters)



SYMBOL	Millimeters		Inches		
STIMBOL	Min.	Max.	Min.	Max.	
A	19.70	20.30	0.776	0.799	
В	16.51	17.02	0.650	0.670	
С	0.62	1.02	0.024	0.040	
D	4.97	5.97	0.196	0.235	
E	0.88	1.22	0.034	0.048	
F	8.46	9.06	0.333	0.357	
G	2.04	2.54	0.080	0.100	
н	0.61	0.92	0.024	0.037	
I	3.19	4.19	0.125	0.165	
J	6.95	7.55	0.274	0.297	
К	2.21	2.71	0.087	0.106	
L	5.08		0.200		

Mechanical Dimensions PRM3-SM (Inches/Millimeters)

J.



SYMBOL	MillImeters		Inches	
STNIDOL	Min.	Max.	Min.	Max.
Α	19.70	20.30	0.776	0.799
В	5.08		0.200	
С	0.62	1.02	0.024	0.040
D	10.38	12.98	0.408	0.511
E	0.88	1.22	0.034	0.048
F	8.46	9.06	0.333	0.357
G	9.24	9.85	0.363	0.388
Н	0.61	0.92	0.024	0.037
I	3.19	4.19	0.125	0.165
J	6.95	7.55	0.273	0.298
к	2.40	2.60	0.094	0.103



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